Motivation for GRU & LSTM:

Z LEXU = P (1) + (MX) - X CO + (wa) T. a <T>LIJ $C1300 \leftarrow C1300 \leftarrow C1300$ a (2011) = tank (2(1)) 6" Wa 60 x b 10 way wx (1)

Back propagation is complicated.

One of the terms involved looks like:

. term for each thre step

· Potential problem if these terms are close to 0 (vonishing gradient) on

very large (exploding gradient)!!

But no big deal if 30 < + > 10 = 1

I no big deal if a CHOLI] = a CH-1>[1] (simplified)

Main idea of GRU: make it so sometimes, a <= DEIJ

- · Hemporarily, rename to c<+> instead of a<+> ? c for "memory cell"
- · Generale a gade of some shape as CET where #'s are approx. Oor 1:

 The = or (bu + (Whic) T. CET-17 (Whit) T CET)
- · for entires where update gent is 1, use new value in 2000 (to 1)

 C(+)[1] [Tub * 20(+)[1] (1-Tu) * C(+-1)[1] element wase products

GRU (Gated Recurrence Unit)

· Add one more thing:

a gate Tr (for relevance) saying which elements

the form of C<+1) are used for calculating c⁴?

(which are relevant?)

upoble gale: $\Gamma_{u} = \sigma \left(\frac{100}{100} + \left(\frac{100}{100} \right)^{T} \cdot c^{24-10} + \left(\frac{100}{100} \right)^{T} \cdot c^{4-10} \right)$ relevance gate: $\Gamma_{r} = \sigma \left(\frac{100}{100} + \left(\frac{100}{100} \right)^{T} \cdot c^{4-10} + \left(\frac{100}{100} \right)^{T} \cdot c^{4-10} \right)$ remove cell proposal: $\tilde{C}^{(4)} = \tanh \left(\frac{100}{100} + \left(\frac{100}{100} \right)^{T} \cdot \left(\frac{100}{100} + \left(\frac{100}{100} \right)^{T} \cdot c^{4-10} \right) \right)$ memory cell: $c^{(4)} = r^{(4)} = r^{(4$

Call of this happens within I cell/circle instead of just zer and acts!

LSTM (Long Short Term Memory)

. Same basic set up as GRU

. Different configuration of Gates

- no relevance gode

+ add a "forget" gode used in place of (1-Tu)

+ odd an "output" gode used to get a from c tt>

update gate: $\Gamma_{i} = \cdots$ figet gate: $\Gamma_{f} = \cdots$ output gate: $\Gamma_{0} = \cdots$ memory cell proposal: $C \stackrel{(+)}{\subset} E^{ij} = trnh \left(160 b_{c}^{[ij]} + (w_{cc})^{T} \cdot C \stackrel{(+)}{\leftarrow} E^{ij} + (w_{cx})^{T} \times C^{(+)} E^{ij} \right)$ memory cell: $C \stackrel{(+)}{\subset} E^{ij} = \Gamma_{0} \stackrel{(+)}{\times} E^{ij} + \Gamma_{f} \times C \stackrel{(+)}{\leftarrow} E^{ij}$ activation adjust: $C \stackrel{(+)}{\subset} E^{ij} = \Gamma_{0} \stackrel{(+)}{\times} E^{ij}$ Tinstead of $(1 - \Gamma_{0})$ "forget" previous memory cell environs where $\Gamma_{0} = 0$, beep ones when $\Gamma_{0} = 1$.